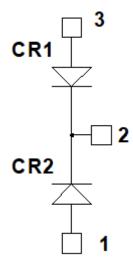


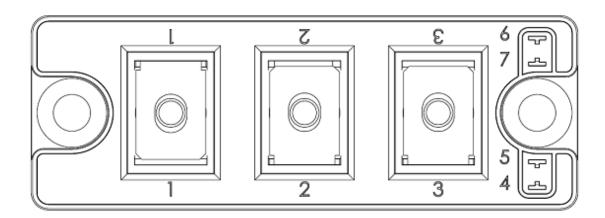
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MSCDC200KK120D1PAG Dual Common Cathode SiC Diodes Power Module

1 Product Overview

This section shows the product overview of the MSCDC200KK120D1PAG device.





All ratings at $T_j = 25$ °C, unless otherwise specified.

Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures should be followed.



1.1 Features

The following are key features of the MSCDC200KK120D1PAG device:

- Silicon carbide (SiC) Schottky diode
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature-independent switching behavior
 - Positive temperature coefficient on VF
- M5 power connectors
- Aluminum nitride (AIN) substrate for improved thermal performance

1.2 Benefits

The following are benefits of the MSCDC200KK120D1PAG device:

- Stable temperature behavior
- Low losses
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- RoHS compliant

1.3 Applications

The MSCDC200KK120D1PAG device is designed for the following applications:

- Welding converters
- Switched Mode power supplies
- Uninterrupted power supplies
- Motor control



2 Electrical Specifications

This section shows the electrical specifications of the MSCDC200KK120D1PAG device.

2.1 Absolute Maximum Ratings

The following table shows the absolute maximum ratings per SiC diode of the MSCDC200KK120D1PAG device.

Table 1 • Absolute Maximum Ratings

Symbol	Parameter		Maximum Ratings	Unit
V _{RRM}	Repetitive peak reverse voltage		1200	V
l _F	DC forward current	Tc = 95 °C	200	А

The following table shows the thermal and package characteristics of the MSCDC200KK120D1PAG.

Table 2 • Thermal and Package Characteristics

Symbol	Characteristic		•	Min	Max	Unit
Visol	RMS isolation voltage, any terminal to case t =	=1 minute, 50 Hz/60	Hz	4000		V
Tı	Operating junction temperature range		-40	175	°C	
Тлор	Recommended junction temperature under so	witching conditions		-40	T _{Jmax} – 25	
Тѕтс	Storage temperature range			-40	125	
Tc	Operating case temperature			-40	125	
Torque	Mounting torque	For terminals	M5	2	3.5	N.m
		To Heatsink	M6	3	5	
Wt	Package weight				160	g

2.2 Electrical Performance

The following table shows the electrical characteristics per SiC diode of the MSCDC200KK120D1PAG.

Table 3 • Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
VF	Diode forward voltage	I _F = 200 A	T _j = 25 °C		1.5	1.8	V
			T _j = 175 °C		2.1		-
Irm	Reverse leakage current	V _R = 1200 V	T _j = 25 °C		60	800	μΑ
			T _j = 175 °C		1000		-
Q c	Total capacitive charge	V _R = 600 V			896		nC
С	Total capacitance	f = 1 MHz, V _R = 400 V			984		pF
		f = 1 MHz, V _R = 800	O V		728		-
RthJC	Junction-to-case thermal resistance					0.16	°C/W



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2.3 Performance Curves

This section shows the typical performance curves for the MSCDC200KK120D1PAG device.

Figure 1 • Maximum Transient Thermal Impedance

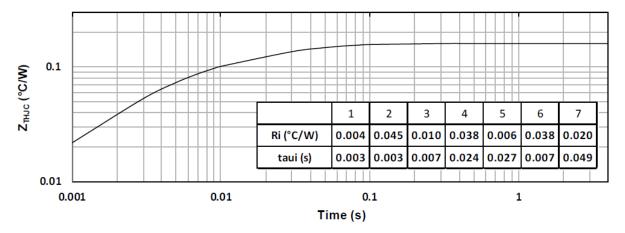


Figure 2 • Forward Current vs. Forward Voltage

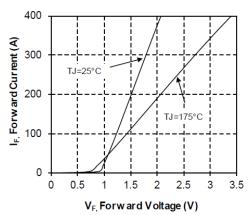
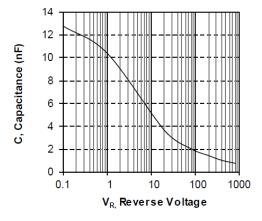


Figure 3 • Capacitance vs. Reverse Voltage





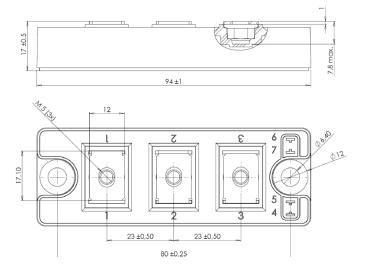
Package Specification 3

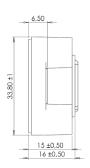
This section shows the package specification for the MSCDC200KK120D1PAG device.

3.1

Package Outline Drawing
The package outline of the MSCDC200KK120D1PAG device is illustrated in this section. The dimensions in the following figure are in millimeters.

Figure 4 • Package Outline Drawing









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